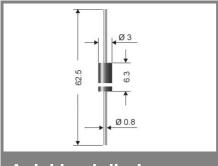
BY 226S, BY 227S, BY 228S



Axial lead diode

Standard silicon rectifier diodes

BY 226S, BY 227S, BY 228S

Forward Current: 1,5 A

Reverse Voltage: 450 to 1500 V

Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

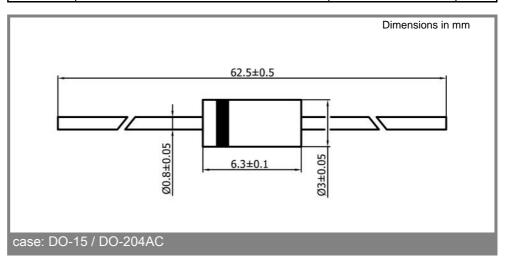
Mechanical Data

- Plastic case DO-15 / DO-204AC
- Weight approx.: 0,4 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 1700 pieces per ammo
- Valid, if leads are kept at ambient temperature at a distance of 10 mm from
- 2) $I_F = 1.5 \text{ A}, \text{ Tj} = 25 \,^{\circ}\text{C}$
- 3) T_A = 25 °C

Туре	Repetitive peak reverse voltage	Surge peak reverse voltage	Max. reverse recovery time	Max. forward voltage
			I _F = - A I _R = - A I _{RR} = - A	
	V _{RRM} V	V _{RSM} V	t _{rr}	V _F ²⁾
BY226S	450	650	-	1,3
BY227S	800	1250	-	1,3
BY228S	1500	1800	-	1,3

Absolute Maximum Ratings Tc = 25 °C, unless otherwise specified					
Symbol	Conditions	Values	Units		
I _{FAV}	Max. averaged fwd. current, R-load, T _A = 50 °C ¹⁾	1,5	Α		
I _{FRM}	Repetitive peak forward current f > 15 Hz ¹⁾	10	Α		
I _{FSM}	Peak forward surge current 50 Hz half sinus-wave ³⁾	50	Α		
i²t	Rating for fusing, t < 10 ms ³⁾	12,5	A²s		
R _{thA}	Max. thermal resistance junction to ambient 1)	45	K/W		
R _{thT}	Max. thermal resistance junction to terminals 1)	-	K/W		
T _j	Operating junction temperature	-50+175	°C		
T _s	Storage temperature	-50+175	°C		

Characte	ristics Tc = 25 °C	Tc = 25 °C, unless otherwise specified		
Symbol	Conditions	Values	Units	
I _R	Maximum leakage current, $T_j = 25 ^{\circ}\text{C}$; $V_R = V_{RRM}$	<10	μΑ	
	$T_j = 100 ^{\circ}\text{C}; V_R = V_{RRM}$	<50	μΑ	
С	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF	
Q _{rr}	Reverse recovery charge $(U_R = V; I_F = A; dI_F/dt = A/ms)$	-	μC	
E _{RSM}	Non repetitive peak reverse avalanche energy ($I_R = mA; T_j = ^{\circ}C;$ inductive load switched off)	-	mJ	



BY 226S, BY 227S, BY 228S

